

TPS92410 用于离线 LED 驱动器的开关控制直接驱动线性控制器

1 特性

- 乘法器适用于优良 PFC、线路调节和低 THD
- V_{IN} 范围从 9.5V 至 450V
- 与相位调光器兼容
- 模拟调光输入时关闭 LED
- 可编程过压保护
- 高精度 3V 基准
- 温度折返
- 热关断
- 无需电感器
- 13 引脚，高压，SOIC 封装

2 应用

- LED 驱动器
- LED 照明灯泡更换

3 说明

TPS92410 是一款具有高压启动功能的先进线性驱动器，适用于低功耗离线 LED 照明应用。该器件可与 TPS92411 直接驱动开关结合使用，用于调节流过 LED 的平均电流。

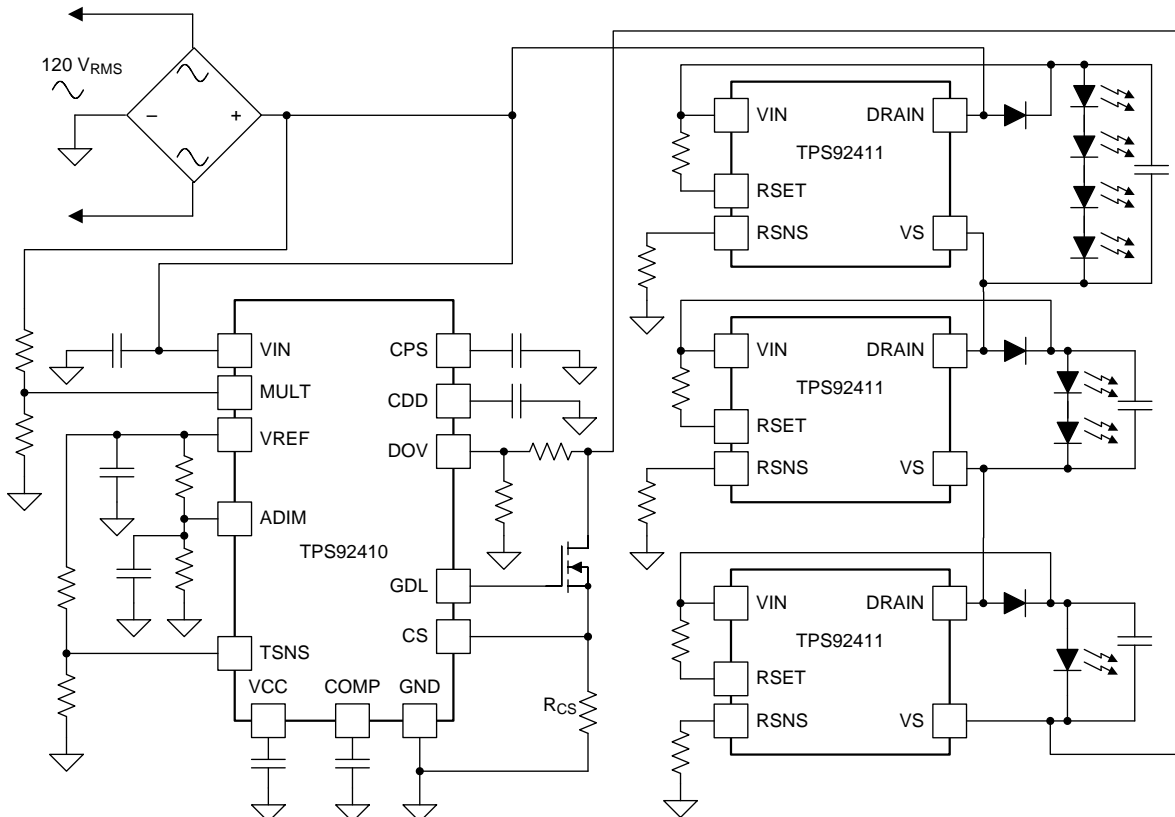
TPS92410 设有基准电压，可用于设定电流级别和温度折返阈值。此器件内含乘法器，可用于获取优异的功率因数同时保持良好的线路调节性能。其它特性包括：欠压锁定、过压保护、正向相位调光器检测、切换到恒流模式、温度折返以及热关断。

器件信息⁽¹⁾

| 部件号 | 封装 | 封装尺寸 (标称值) |
|-----------|-----------|-----------------|
| TPS92410D | SOIC (13) | 8.65mm x 6.00mm |

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

简化电路原理图



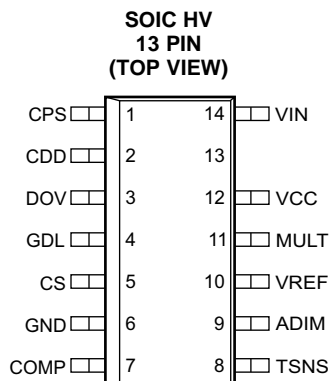
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4 修订历史记录

| 日期 | 修订版本 | 注释 |
|------------|------|-------|
| 2014 年 6 月 | * | 最初发布。 |

5 Pin Configuration and Functions



Pin Functions

| PIN | | TYPE ⁽¹⁾ | DESCRIPTION |
|------|-----|---------------------|---|
| NAME | NO. | | |
| ADIM | 9 | I | Analog input used to set the reference of the linear controller. A 0-V to 1.5-V signal on ADIM sets the current sense reference level. |
| CDD | 2 | I/O | A capacitor to ground sets the time interval for dimmer detection. Tie to GND if no phase dimmer operation is required. |
| COMP | 7 | I/O | Compensation for control loop. Connect a capacitor from the COMP pin to ground. |
| CPS | 1 | I/O | A capacitor to ground sets the length of the CDD pin charge pulse. Leave open if no phase dimmer operation is required. |
| CS | 5 | I | Current sense input used for linear regulator. |
| DOV | 3 | I | Input to monitor linear MOSFET drain voltage. A resistor divider from the DOV pin to the drain connection of the MOSFET monitors MOSFET over-voltage. Add a capacitor to GND for filtering. |
| GDL | 4 | O | Gate drive for an external linear MOSFET. |
| GND | 6 | G | Chip ground return. |
| MULT | 11 | I | AC input to the multiplier. Tap a resistor divider off the rectified line to this pin. |
| TSNS | 8 | I | Thermal sense input. Connect to a resistor and NTC thermistor for thermal foldback. |
| VCC | 12 | I/O | Pre-regulated voltage. Connect a bypass capacitor to ground. |
| VIN | 14 | P | High voltage input. Provides power to the device. |
| VREF | 10 | O | 3-V voltage supply reference. Source used for TSNS input. |

(1) I = Input, O = Output, P = Supply, G = Ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

| | | MIN | MAX | UNIT |
|---|--|------|-----|------|
| Input voltage | VIN | -0.3 | 700 | V |
| Output voltage | VCC | -0.3 | 18 | V |
| | GDL | -0.3 | 18 | |
| | MULT, VREF, ADIM, COMP, CPS, CDD, TSNS | -0.3 | 7.7 | |
| | DOV | -0.3 | 6 | |
| Source current | CS | | 1 | mA |
| Sink current | CS | | 1 | mA |
| Operating junction temperature, T _J ⁽²⁾ | | -40 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum junction temperature is internally limited by the device.

6.2 Handling Ratings

| | | MIN | MAX | UNIT |
|-----------------------------------|---------------------------|--|-----|------|
| T _{stg} | Storage temperature range | -65 | 150 | °C |
| V _(ESD) ⁽¹⁾ | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽²⁾ | | kV |
| | | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽³⁾ | | V |

- (1) Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges into the device.
- (2) Level listed above is the passing level per ANSI/ESDA/JEDEC JS-001. JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process. *Terminals listed as 1000V may actually have higher performance.*
- (3) Level listed above is the passing level per EIA-JEDEC JESD22-C101. JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process. *Terminals listed as 250V may actually have higher performance.*

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|-------------------|--------------------------------|-----|-----|-----|------|
| V _{IN} | Input voltage | 9.5 | | 450 | V |
| V _{MULT} | Multiplier peak input voltage | | | 3 | V |
| V _{ADIM} | Analog dimming input voltage | 0 | | 3 | V |
| T _J | Operating junction temperature | -40 | | 125 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | TPS92410 | UNIT |
|-------------------------------|--|----------|------|
| | | D (13) | |
| R _{θJA} | Junction-to-ambient thermal resistance | 84.8 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 39.8 | |
| R _{θJB} | Junction-to-board thermal resistance | 39.5 | |
| Ψ _{JT} | Junction-to-top characterization parameter | 8.9 | |
| Ψ _{JB} | Junction-to-board characterization parameter | 39.0 | |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | |

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

 $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$, $V_{VIN} = 100\text{ V}$, $V_{ADIM} = V_{MULT} = 1\text{ V}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|---|-------|-------|-------|------|
| SUPPLY VOLTAGE (VIN) | | | | | | |
| VCC | Pre-regulator output voltage | | | 10.15 | | V |
| VCC _{UVLO} | Supply voltage undervoltage protection | Rising threshold, $V_{VIN} = V_{VCC}$ | | 8 | 8.3 | V |
| | | Falling threshold, $V_{VIN} = V_{VCC}$ | 5 | 5.85 | | |
| | | Hysteresis | | 2.15 | | |
| I _{VIN} | Input voltage bias current | $V_{VCC} = 12\text{ V}$ | | 2.5 | 50 | μA |
| I _{VCC} | Supply bias current | | | 305 | 500 | μA |
| | Supply standby current | $V_{VIN} = 0\text{ V}$, $V_{VCC} = 7\text{ V (UVLO)}$ | | 145 | | |
| I _{VCC} LIM | VCC supply current limit | $V_{VCC} = 7.5\text{ V}$ | 8 | | 25 | mA |
| T _{plh(UVLO)} | VCC supply glitch filter rising | V_{VCC} stepped from 6.075 V to 110% of $V_{VCC\text{UVLO,rising}}$ | | 16.2 | | μs |
| MULTIPLIER (MULT) | | | | | | |
| V _{MULT,LINEAR} | Multiplier linear range | | 0 | | 3.5 | V |
| V _{COMP,LINEAR} | COMP pin linear range | | 1.5 | | 3.25 | V |
| R _{MULT} | Input impedance | | 500 | 580 | 700 | kΩ |
| A _{MULT} | Multiplier gain | $V_{MULT} = 1.5\text{ V}$, $V_{COMP} = 2.25\text{ V}$, $k = V_{MULT_OUT}/[(V_{COMP}-1.5\text{ V}) \times V_{MULT}]$ | 0.95 | 1.43 | 1.85 | 1/V |
| V _{MULT,OFFSET} | Multiplier output offset | $V_{MULT} = 0\text{ V}$, $V_{COMP} = 2.25\text{ V}$ | | 13.7 | | mV |
| MULT _{OUT,mx} | Multiplier Output Clamp Voltage | $V_{ADIM} = V_{TSNS} = \text{open}$; $V_{COMP} = 4\text{ V}$, $V_{MULT} = 3.5\text{ V}$ | 2.25 | 2.43 | 2.65 | V |
| VOLTAGE REFERENCE (VREF) | | | | | | |
| V _{VREF} | Reference voltage | $I_{VREF} = 100\text{ μA}$ | 2.85 | 3 | 3.15 | V |
| V _{REF,LINE} | Line regulation | $8.5\text{ V} \leq V_{VIN} \leq 100\text{ V}$ | | | 1% | |
| V _{REF,LOAD} | Load regulation | $10\text{ μA} \leq I_{REF} \leq 200\text{ μA}$ | | | 1% | |
| TRANSCONDUCTANCE AMPLIFIER (ADIM, COMP) | | | | | | |
| ADIM _{LIM} | ADIM operating voltage limit | | 1.425 | 1.5 | 1.575 | V |
| I _{ADIM} | Pull-up current | | | 0.5 | 1 | μA |
| ADIM _{SD} | ADIM linear shutdown threshold | Falling | 18 | 40 | 70 | mV |
| ADIM _{SD,HYS} | ADIM shutdown hysteresis | | | 20 | | mV |
| g _M | Transconductance | | | 43.3 | | μS |
| V _{OFFSET} | Input offset voltage | $V_{ADIM} = 0.5\text{ V}$ | -20 | | 20 | mV |
| I _{OUT,SOURCE} | Output source current | $V_{COMP} = 2.25\text{ V}$, $V_{MULT} = 0\text{ V}$, $V_{ADIM} = V_{TSNS} = 2\text{ V}$ | | 65 | | μA |
| I _{OUT,SINK} | Output sink current | $V_{COMP} = 2.25\text{ V}$, $V_{TSNS} = 0\text{ V}$ | | 75 | | |
| I _{START} | | $V_{COMP} = 0\text{ V}$, $V_{ADIM} = 0\text{ V}$ | | 485 | | |
| DIMMER DETECT (MULT, CPS, CDD) | | | | | | |
| I _{CPS} | Charge current for CPS pin | | 6.7 | 10 | 13.3 | μA |
| I _{CDD,c} | Charge current for CDD pin | | 5.7 | 10 | 13.3 | |
| I _{CDD,d} | Discharge current for CDD pin | | 0.67 | 1 | 1.33 | |
| Dv/Dt | Maximum detection threshold | V_{MULT} stepped from 0 V to 1 V, minimum slew rate required | | 1/100 | | V/μs |
| V _{OFFSET} | Detector offset voltage | | | 0.41 | | V |
| V _{TH,CDD} | CDD threshold | | | 1.5 | | |
| V _{TH,CPS} | CPS threshold | | | 1.5 | | |
| R _{CSP} | Pull down R _{DS(on)} | | | 314 | | |

Electrical Characteristics (continued)
 $-40^{\circ}\text{C} \leq T_J \leq 125^{\circ}\text{C}$, $V_{\text{VIN}} = 100\text{ V}$, $V_{\text{ADIM}} = V_{\text{MULT}} = 1\text{ V}$ (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------------|---|--|-------|-------|-------|--------------------|
| DRAIN OVER-VOLTAGE (DOV) | | | | | | |
| $V_{\text{TH,DOV}}$ | Drain over-voltage threshold | | 1.38 | 1.5 | 1.62 | V |
| $V_{\text{HYS,DOV}}$ | Internal DOV hysteresis | | | 20 | | mV |
| $I_{\text{HYS,DOV}}$ | Drain over-voltage source current | $V_{\text{DOV}} = 1.5\text{ V}$, Device in over-voltage mode | 0.7 | 1 | 1.5 | μA |
| $V_{\text{REF,DOV}}$ | Linear CS reference during over-voltage | $V_{\text{DOV}} = 1.75\text{ V}$ | | 0.1 | | V |
| THERMAL FOLDBACK (TSNS) | | | | | | |
| TSNS_{LIM} | TSNS operating voltage limit | | 1.425 | 1.5 | 1.575 | V |
| | | $V_{\text{ADIM}} = V_{\text{TSNS}} = 1\text{ V}$, Measure reference to the linear error amplifier | | 2.1 | | mV |
| | | $V_{\text{TSNS}} = 0\text{ V}$, Measure reference to the linear error amplifier | | 3.6 | | |
| I_{TSNS} | Pull-up current | | | 0.5 | 1 | μA |
| LINEAR CURRENT SENSE (CS) | | | | | | |
| $V_{\text{CS(max)}}$ | CS voltage level (CC dimming mode) | $2.5\text{ V} = V_{\text{ADIM}} = V_{\text{TSNS}}$ | 1.425 | 1.5 | 1.575 | V |
| $V_{\text{CS(max)}}$ | CS voltage level (PFC mode) | $2.5\text{ V} = V_{\text{ADIM}} = V_{\text{TSNS}}$ | 1.125 | 1.291 | 1.425 | |
| V_{IO} | Input offset voltage | $V_{\text{REF}} = 1\text{ V}$ | -17 | 2.57 | 17 | mV |
| $V_{\text{CMR-}}$ | Minimum input common mode range | | | 0 | | V |
| GATE DRIVER (GDL) | | | | | | |
| V_{OH} | High-level output voltage, GDL | $I_{\text{LOAD}} = -1\text{ mA}$ | 6.5 | 8.2 | | V |
| V_{OL} | Low-level output voltage, GDL | $I_{\text{LOAD}} = 1\text{ mA}$ | | 0.152 | 0.45 | |
| $I_{\text{OUT(src)}}$ | Output source current | $V_{\text{GDL}} = 4\text{ V}$ | 2.5 | 8.1 | | mA |
| $I_{\text{OUT(snk)}}$ | Output sink current | $V_{\text{GDL}} = 4\text{ V}$ | 2.5 | 11.9 | | |
| THERMAL SHUTDOWN | | | | | | |
| T_{SD} | Thermal shutdown | | | 175 | | $^{\circ}\text{C}$ |
| | Thermal shutdown hysteresis | | | 10 | | |

6.6 Typical Characteristics

Unless otherwise stated, $-40^{\circ}\text{C} \leq T_A = T_J \leq +125^{\circ}\text{C}$. All characterization circuits are fully EMI compliant and phase dimmable.

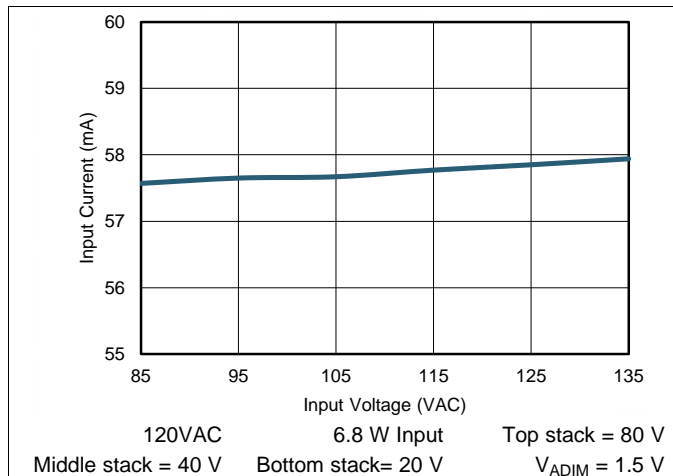


Figure 1. System Input Current vs Input Voltage

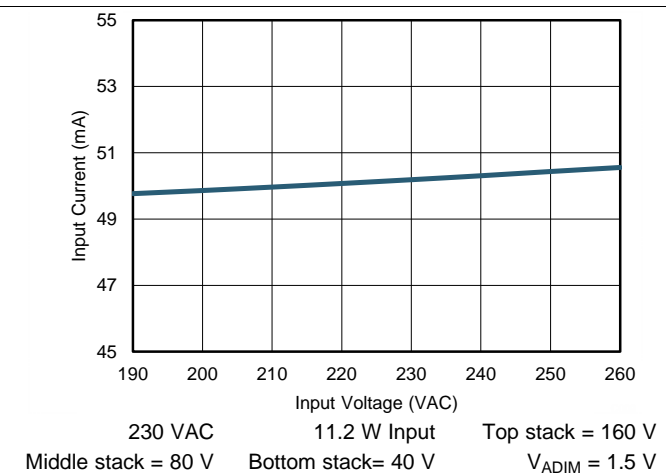


Figure 2. System Input Current vs Input Voltage

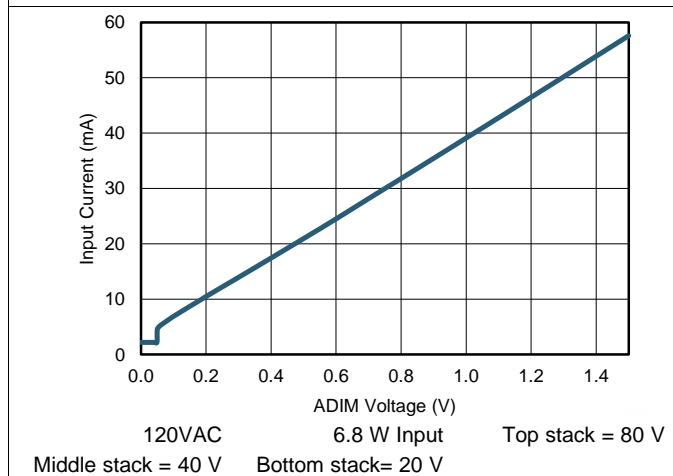


Figure 3. System Input Current vs ADIM Voltage

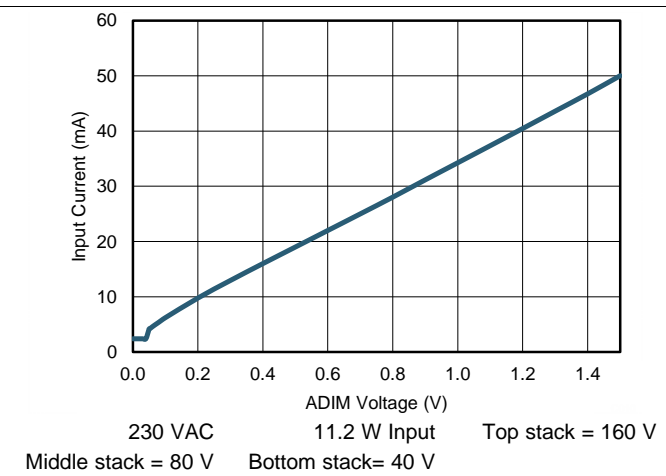


Figure 4. System Input Current vs ADIM Voltage

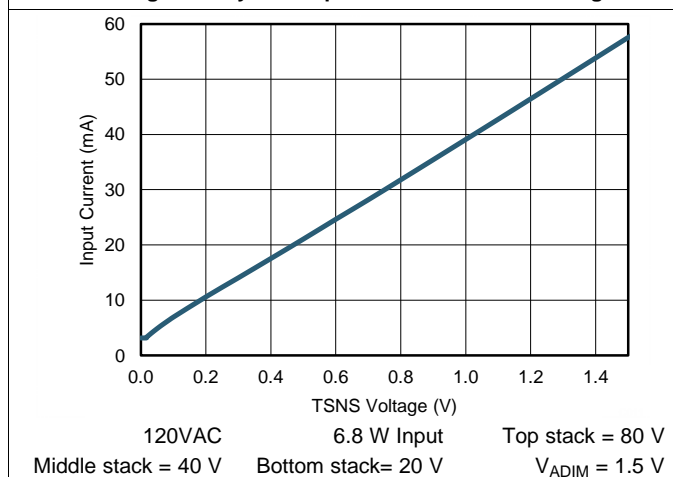


Figure 5. System Input Current vs TSNS Voltage

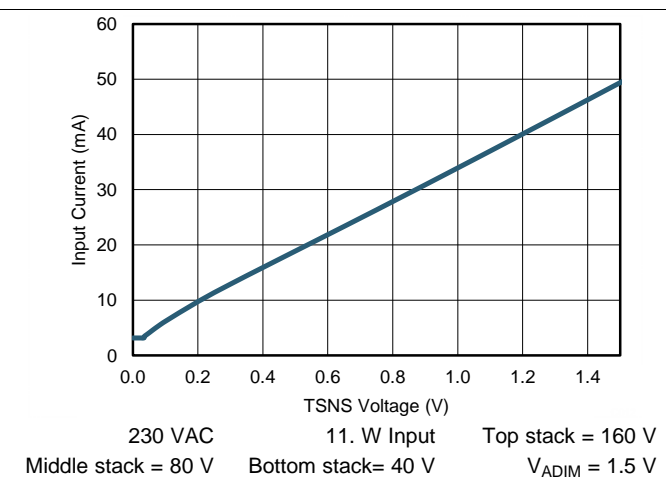


Figure 6. System Input Current vs TSNS Voltage

Typical Characteristics (continued)

Unless otherwise stated, $-40^{\circ}\text{C} \leq T_A = T_J \leq +125^{\circ}\text{C}$. All characterization circuits are fully EMI compliant and phase dimmable.

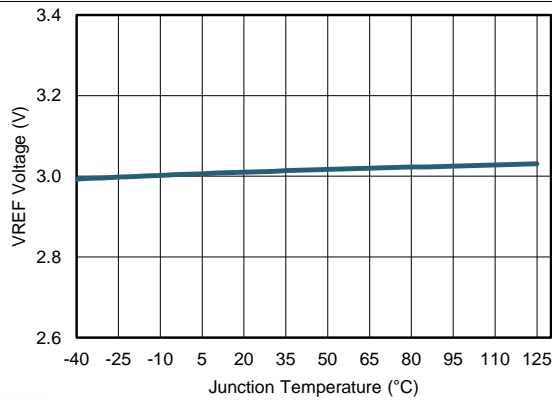


Figure 7. VREF Voltage vs Temperature

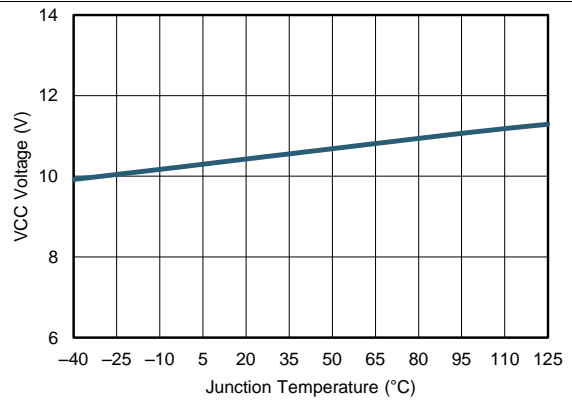


Figure 8. VCC Voltage vs Temperature

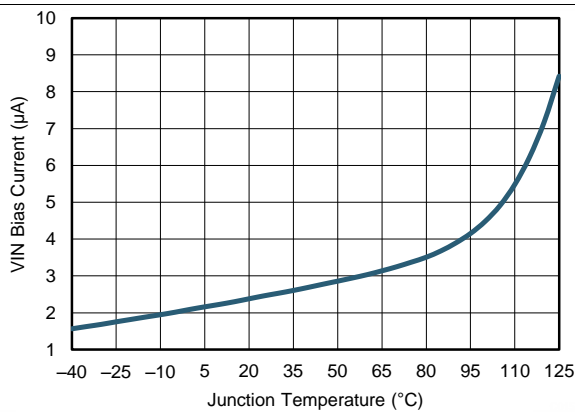


Figure 9. VIN Bias Current vs Temperature

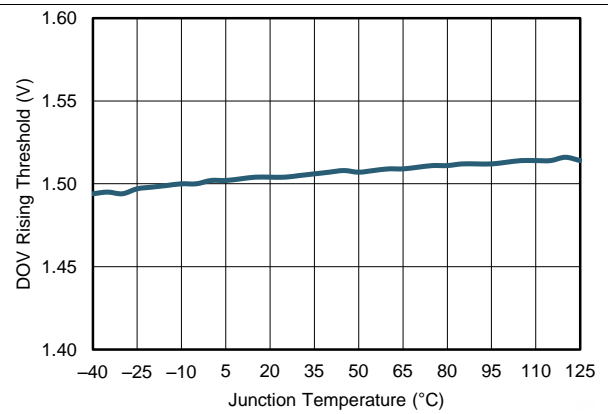


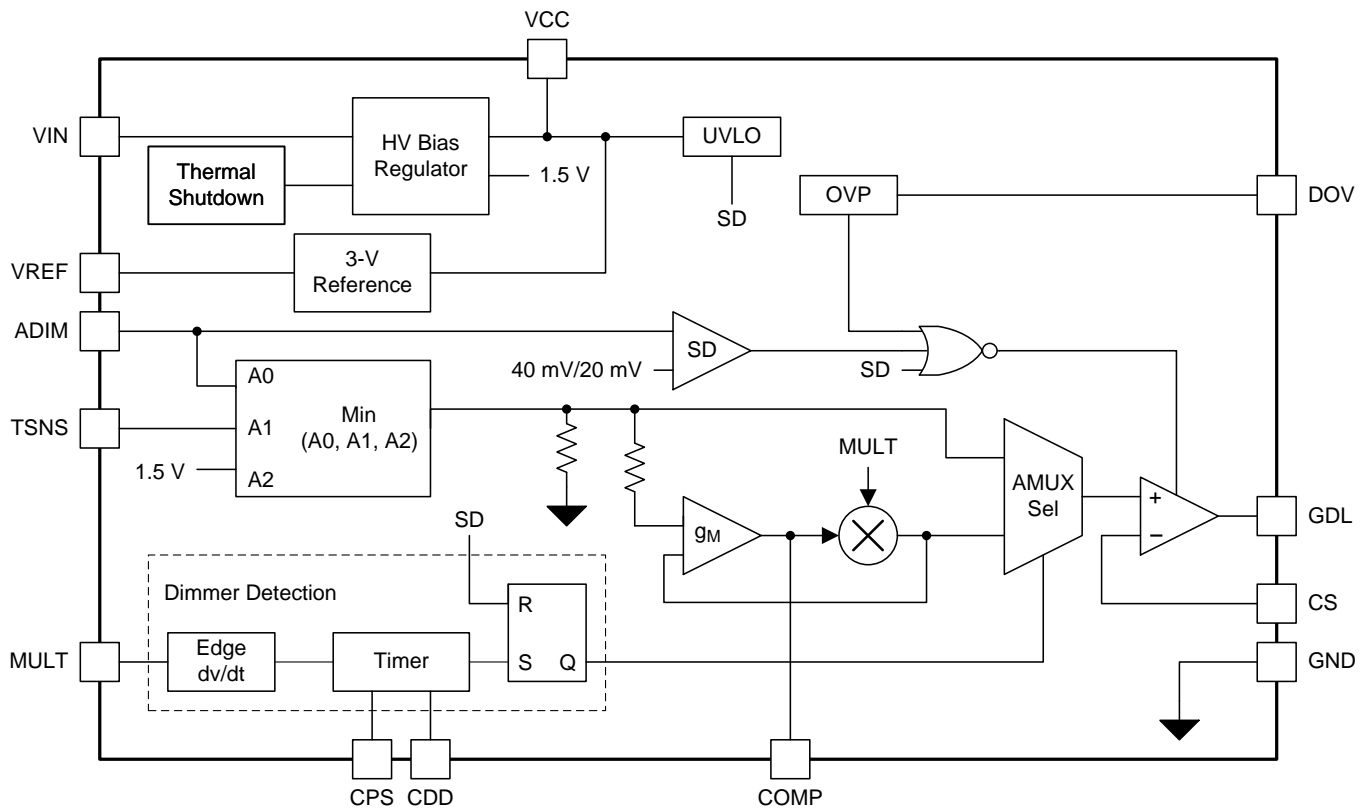
Figure 10. Over-voltage Threshold vs Temperature

7 Detailed Description

7.1 Overview

The TPS92410 device is a high-voltage linear regulator driver that can be used for offline LED drivers. It includes a feature that forces the regulator current to follow the rectified AC voltage to achieve high power-factor and low total harmonic distortion (THD). When the device detects multiple forward phase dimmer edges, the regulator current changes to a DC level to maintain a DC current draw to provide for a triac dimmer's hold current requirements. The TPS92410 device also includes linear MOSFET over-voltage protection to protect the MOSFET if the LEDs are shorted. It includes a thermal foldback feature to protect the entire circuit in the event it becomes overheated. Analog dimming capability allows light output to be controlled by a microcontroller or a 0 V to 10 V dimmer. The device also includes a precision voltage reference.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Setting the Linear Regulator Current/Input Power (CS)

The input power (P_{IN}) can be set with a resistor from the CS pin to ground. Calculate the value of the R_{CS} resistor using the following equation (see [Figure 11](#)):

$$R_{CS} = \frac{V_{IN(rms)} \times 1.428}{P_{IN}}$$

where

- $V_{IN(rms)}$ is the nominal rms input voltage to the circuit (1)

This sets the input power level due to the linear regulator for a standard application with V_{ADIM} and V_{TSNS} greater than or equal to 1.5 V. If either pin is pulled below 1.5 V the input power scales accordingly to the ratio of $V_{TSNS}/ADIM/1.5$ V. The actual input power of the circuit is higher due to variables such as V_{IN} bias current, resistor, diode, and other losses. When using forward phase dimmers there can be a significant current spike through the MOSFET and R_{CS} depending on the dv/dt of the dimmer edge. The magnitude and duration of this current spike should be measured in any application and a resistor should be chosen that is rated for the peak current required in any final design.

7.3.2 Over-Voltage Protecton (DOV)

The DOV pin can be used to set an over-voltage protection threshold for the external linear MOSFET. During normal operation DOV is not active, but in the event that the LEDs become shorted resulting in excessive voltage and power dissipation in the MOSFET over-voltage protection becomes active. During an over-voltage event, the CS pin regulation voltage defaults to 100 mV to reduce power dissipation in the MOSFET but still provide some light with the remaining LEDs. For this reason it is recommended to use a nominal value for CS for normal operation higher than 100 mV. A resistor divider to DOV between the MOSFET drain and system ground sets this over-voltage level as shown in [Figure 11](#). During an over-voltage event the DOV pin sources 1 μ A to provide some hysteresis. The level and hysteresis can be set using the following equations:

$$R_{DRAIN} = R_{GROUND} \times \frac{V_{OVP} - 1.5 \text{ V}}{1.5 \text{ V}} \quad (2)$$

$$V_{HYS-DOV} = 20 \mu\text{A} \times R_{DRAIN}$$

where

- V_{OVP} is the desired maximum drain voltage
- R_{DRAIN} is the resistor from DOV to the drain
- R_{GROUND} is the resistor from DOV to system ground (3)

Include a capacitor from the DOV pin to system ground to prevent the circuit from transitioning into over-voltage protection mode during the start-up sequence. A recommended value for the R_{GND} resistor is 121 k Ω in parallel with a 4.7- μ F capacitor for most applications. R_{DRAIN} can then be calculated. To calculate the values of R_{GND} and C_{GND} for a particular application you need to set the time constant to be longer than it takes to charge up the highest voltage LED string capacitor to prevent a false trip of the over-voltage protection during start-up. This time constant and the resulting RC can be found using the following equations:

$$dt = \frac{C_{UPPER} \times V_{UPPER}}{I_{UPPER}} \quad (4)$$

$$R_{GND} \times C_{GND} = 5 \times dt$$

where

- dt is the time constant to charge the LED capacitor
- C_{UPPER} is the highest voltage LED string capacitor
- V_{UPPER} is the highest string voltage
- I_{UPPER} is the highest voltage LED string current (5)

Choose R_{GND} to be in the 100 k Ω to 150 k Ω range and calculate C_{GND} . Then R_{DRAIN} can be calculated. Over-voltage protection should be adjusted for the minimum string voltages for analog dimming applications or simply disabled by connecting DOV to ground.

Feature Description (continued)

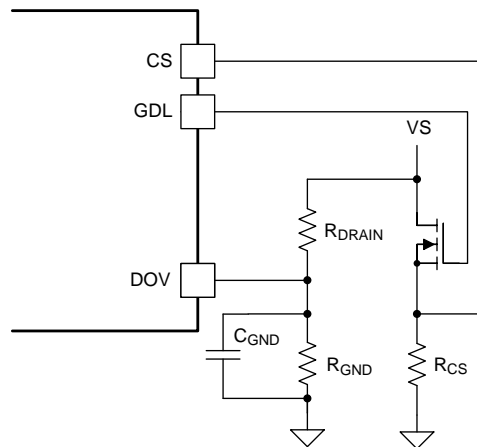


Figure 11. CS and DOV Over-voltage Connections

7.3.3 Input Undervoltage Lockout (UVLO)

The TPS92410 device includes input UVLO protection. This protection prevents the device from operating until a voltage on the VIN pin exceeds 8.0 V. The circuit has 2.15 V of hysteresis to prevent false triggering.

7.3.4 Reference Voltage (VREF)

The TPS92410 includes a 3-V reference feature which can be used to set the DC level on the ADIM pin. It can also source current for the TSNS divider for the thermal foldback circuitry using the TSNS pin. The VREF pin can supply a maximum current of approximately 3 mA but should be limited to less than 200 μ A to minimize power dissipation. All current sourced from VREF is supplied by VIN so power dissipation can become significant when sourcing higher currents.

7.3.5 Forward Phase Dimmer Detection (CPS, CDD)

An edge-detect circuit senses when a forward phase dimmer is connected to the input. This detection feature allows the device to operate with a wide variety of dimmers that operate in either forward or reverse phase. The C_{CPS} and C_{CDD} capacitors assist in this function while preventing a false dimmer detect caused by line glitches and spikes in applications without a phase dimmer. Connect a 0.1- μ F capacitor between CPS to GND and a 1- μ F capacitor from CDD to GND for most applications to use this feature. This results in a time constant of 15 ms for CPS and 150 ms for CDD. If this feature is not required leave CPS open and ground CDD.

The dimmer detect function operates by applying a 10 μ A charging current to both the CPS and CDD capacitors. If no edges are detected the CPS capacitor charges to a 1.5 V threshold at which point the CDD pin switches from sourcing 10 μ A to sinking 1 μ A. This prevents the CDD pin from charging to the 1.5-V threshold that switches the device to dimmer detect mode. When a forward phase dimmer is present the edge is detected at the MULT pin. Each time an edge is detected the CPS pin is discharged and then begins charging again. When enough consecutive edges are present to keep the CPS pin below 1.5 V for longer than the CDD time constant the CDD pin reaches 1.5 V and the device switches to dimmer detect mode. The current regulation level between constant current dimmer detect mode and standard PFC operation can be different depending on dimmer angle. A time constant too long can result in a mild light difference at turn-on due to a slightly different light level between PFC mode at turn-on and dimmer detect mode. A time constant too short could result in unintentionally switching to dimmer detect mode on noisy lines. The easiest way to implement a dimmer detect circuit is to use a CPS time constant just a bit longer than T_{PER} , the period of half of the sine wave input voltage. But other time constants may be used if required. To change the time constants use the following equations:

$$dt_{CPS} = \frac{C_{CPS} \times 1.5 \text{ V}}{10 \mu\text{A}} \quad (6)$$

$$dt_{CDD} = \text{infinite} \quad (\text{for } dt_{CPS} < \frac{T_{PER}}{11}) \quad (7)$$

Feature Description (continued)

$$dt_{CDD} = \frac{C_{CDD} \times 1.5 \text{ V}}{(11 \mu\text{A} \times dt_{CPS}) - (1 \mu\text{A} \times T_{PER})} \quad (\text{for } \frac{T_{PER}}{11} < dt_{CPS} < T_{PER}) \quad (8)$$

$$dt_{CDD} = \frac{C_{CDD} \times 1.5 \text{ V}}{10 \mu\text{A}} \quad (\text{for } dt_{CPS} > T_{PER}) \quad (9)$$

7.3.6 Analog Dimming Input and Setting V_{CS} (ADIM)

If a default CS voltage of lower than 1.291 V is required, it can be set using the ADIM pin. A resistor divider from the reference sets ADIM to any voltage lower than 1.5 V. During normal operation, the CS voltage is equal to 0.86 times the voltage applied to ADIM. The ADIM pin can also be used for analog dimming using a variable voltage between 40 mV and 1.5 V to dynamically change the CS voltage. If the device pulls the ADIM pin below 40 mV, the device pulls the linear MOSFET gate low to shut off the LEDs. Tie an unused ADIM pin to VREF with a 200-k Ω resistor. If a larger analog dimming range is required, use the TSNS pin for analog dimming because it does not disable the linear regulator when the voltage drops below 40 mV. The ADIM and TSNS pins function identically with the exception of the GDL disable threshold on the ADIM pin.

7.3.7 Thermal Foldback (TSNS)

The thermal foldback function of the TPS92410 device behaves similarly to the ADIM function. However, rather than using a resistor divider, a NTC thermistor connects TSNS to system ground. Calculate the temperature at which the circuit begins to reduce current by determining the temperature at which the the TSNS pin drops below 1.5 V (when the ADIM pin is 1.5 V or higher). With a valid external voltage on the ADIM pin (< 1.5 V), the current begins to reduce when the TSNS voltage drops lower than the ADIM voltage. As described in the [Analog Dimming Input and Setting \$V_{CS}\$ \(ADIM\)](#) section, the TSNS pin and the ADIM pin may be used interchangeably. If the TSNS pin is used for analog dimming, the ADIM pin may be used for thermal foldback.

7.3.8 Internal Regulator (VCC)

The VCC pin functions as the output of the internal supply for the device. Connect a 10- μF capacitor between the VCC pin and ground to keep VCC charged for phase dimming applications. For analog dimming or non-dimming applications a 4.7- μF capacitor is sufficient.

7.3.9 Error Amplifier (COMP)

The COMP pin functions as the output of the internal g_m error amplifier. To ensure stability over all conditions, connect a 4.7- μF capacitor between the COMP pin and ground. The bandwidth of the PFC can be calculated using the following equation:

$$BW = \frac{g_m}{2\pi \times C_{COMP}} \quad (10)$$

7.3.10 Linear MOSFET Gate Drive (GDL)

The GDL pin functions as the gate drive for the linear MOSFET that regulates current. Connect the GDL pin to the gate of the power MOSFET. To reduce EMI, connect a 10- Ω resistor in series with a 1- μF capacitor between the GDL pin and the CS pin with a diode connected between them that returns to the VCC pin as show in [Figure 12](#). If phase dimming is not required, the diode can be omitted. Choose a linear MOSFET with a voltage rating of at least 250 V for a 120-VAC input application. Choose a linear MOSFET with a voltage rating of at least 400 V for a 230-VAC input application. The MOSFET voltage rating must take into account the MOV clamp voltage in protected applications as this may be higher than the MOSFET and damage may occur during a surge event. The Safe Operating Area (SOA) of the MOSFET must also be taken into account. During start-up the MOSFET experiences high voltages as the LED capacitors charge. This leads to high power dissipation during start-up that the MOSFET must withstand. Use with forward phase dimmers also causes a significant current spike in the MOSFET when the dimmer fires. The magnitude and duration of this current spike is dependent upon many factors and should be measured in any design to confirm the MOSFET is rated properly for long life operation. MOSFET parasitics should also be considered. A very large MOSFET with high parasitic capacitances can cause erroneous switching of the TPS92411 floating drivers.

Feature Description (continued)

7.3.11 EMI Filter

The input EMI filter requirements are specific to each design. A capacitor is needed for filtering and may also require an input resistor. For forward phase applications a snubber across the capacitor is likely to be required. The input resistor and snubber resistor need to have a pulse rating high enough for the particular application both during start-up and during forward phase dimming.

7.3.12 Thermal Shutdown

The TPS92410 device includes thermal shutdown protection. If the die temperature reaches approximately 175°C the device shuts down. When the die temperature cools to approximately 165°C, the device resumes normal operation.

7.4 Device Functional Modes

7.4.1 Multiplier Mode

When the MULT pin detects full rectified AC voltage, the CS voltage follows the rectified AC waveform around its regulation point. This behavior forces the current that is drawn from the line to follow the AC input voltage waveform. This action results in high power factor and low total harmonic distortion (THD). Line transients are rejected by the time constant that is initially set on the dimmer detect circuit to ensure dimmer detect mode is not engaged by random voltage spikes on the line.

7.4.2 Dimmer Detect Mode

When a forward phase dimmer is present there is a sharp edge presented to the MULT pin each cycle. This forces the dimmer detect circuit past its time constant and the device enters dimming mode. The CS voltage is then set at a DC level to prevent dimmer misfire

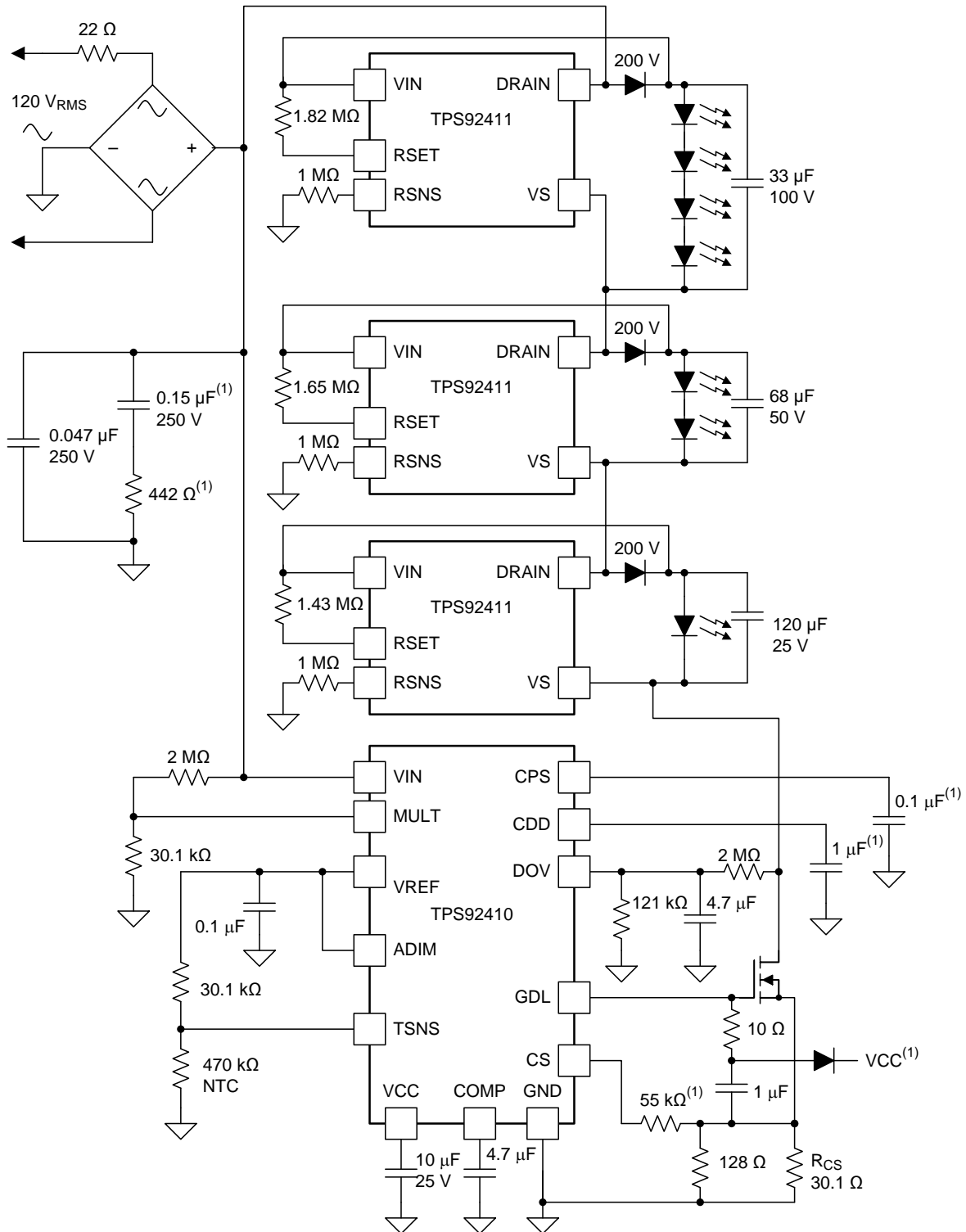
8 Application and Implementation

8.1 Application Information

The TPS92410 is a linear controller designed to be used in conjunction with the TPS92411 switch for high voltage off-line LED drive applications. Typical uses include 120 VAC and 230 VAC input LED drivers with either analog or phase dimming. However like any linear controller it may also be used with a DC input voltage up to 450 V. The following applications are for typical off-line LED drivers with 120 VAC and 230 VAC input voltages.

8.2 Typical Application

8.2.1 120-VAC Input, 6.6-W LED Driver



(1) Required only for forward phase dimmer capability.

Figure 12. 120-V Application Schematic

Typical Application (continued)

8.2.1.1 Design Requirements

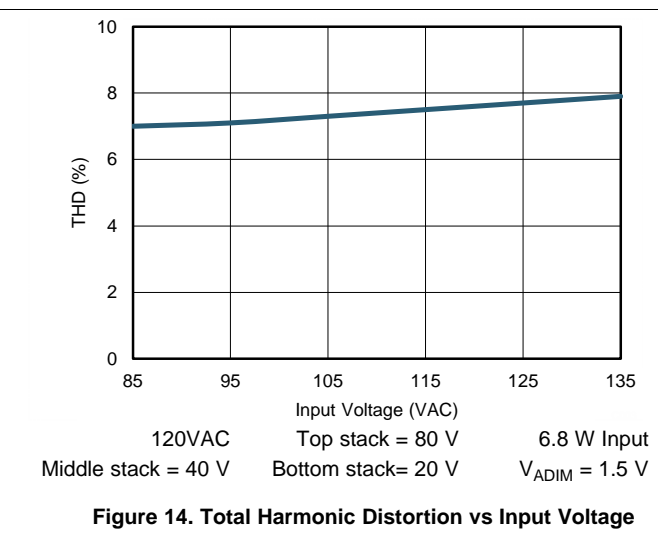
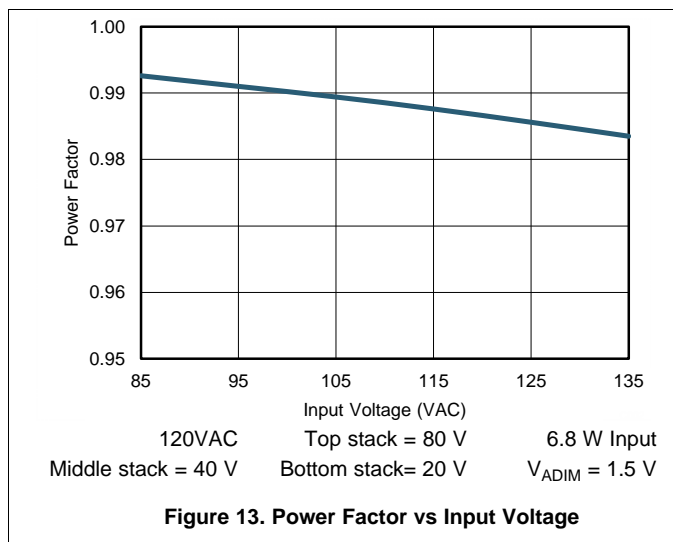
This application requires a 6.6-W input power, high-efficiency, phase-dimmable LED lamp for use on 120-V systems.

8.2.1.2 Detailed Design Procedure

The TPS92411 components are chosen using the guidelines in the TPS92411 datasheet. Most of the values used for the TPS92410 are recommended values for any 120-V system. Connect the input voltage directly to the rectified AC while the MULT pin is connected to a 2-M Ω , 30.1-k Ω resistor divider from the rectified AC to ground. The VREF pin should have a 0.1- μ F capacitor tied to ground for decoupling. The VCC pin should be decoupled using a 10- μ F ceramic capacitor to ground and the COMP pin should have a 4.7- μ F ceramic capacitor to ground. Connect a 0.1- μ F ceramic capacitor from the CPS pin to ground. Connect a 1- μ F ceramic capacitor from the CDD pin to ground to enable phase dimmable operation. This results in a 150 ms dimmer detect time constant. The over-voltage protection using the DOV pin can be set using Equation 3. In this case a MOSFET drain over-voltage level of approximately 27 V is chosen. A 4.7- μ F capacitor should be placed in parallel with a 121-k Ω resistor from the DOV pin to ground to set a time constant and for filtering for all applications.

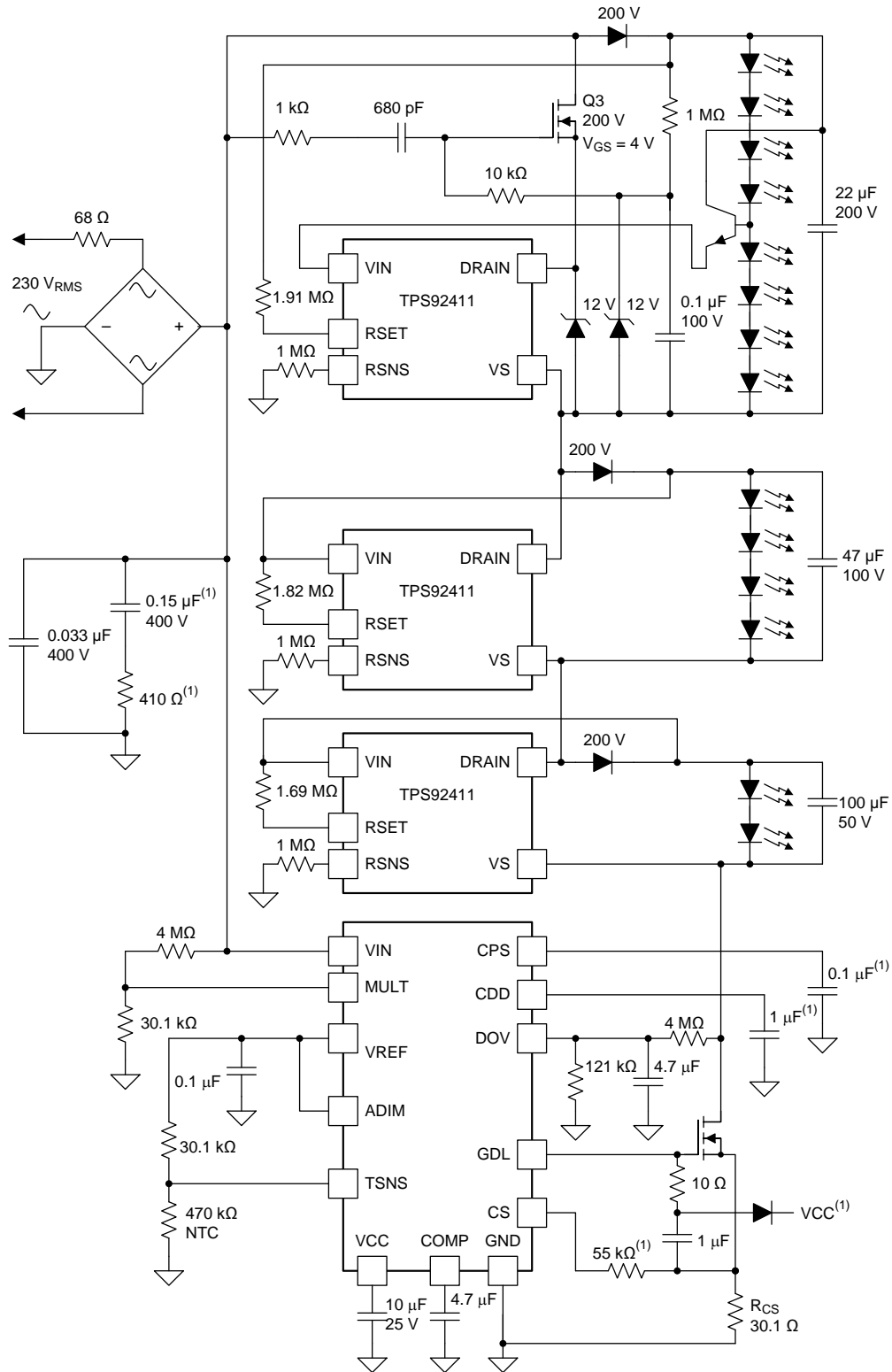
Choose R_{DRAIN} for the appropriate voltage, in this case 2 M Ω is chosen. Connect a 10- Ω resistor in series with a 1- μ F ceramic capacitor from GDL to CS for stability and to help reduce EMI. Place a diode from the center point of these two components to the VCC pin to clamp the voltage on the GDL pin and the CS pin that can become high with some forward phase dimmers. A rating of at least 20 V and 100 mA is recommended with a peak-repetitive current rating of at least 2 A. A 55-k Ω resistor should be connected between the MOSFET source and the CS pin for additional protection. Connect a 30.1-k Ω resistor from the TSNS pin to the VREF pin. The NTC thermistor to ground should be selected so that the desired foldback temperature results in a thermistor value of 30.1 k Ω . R_{CS} is then calculated using Equation 1. R_{CS} = 25 Ω is very close, a 30.1 Ω in parallel with a 182 Ω resulting in about 25.83 Ω was chosen.

8.2.1.3 Application Curves



Typical Application (continued)

8.2.2 230-VAC Input, 11-W LED Driver



(1) Required only for forward phase dimmer capability.

Figure 15. 230-V Application Schematic

Typical Application (continued)

8.2.2.1 Design Requirements

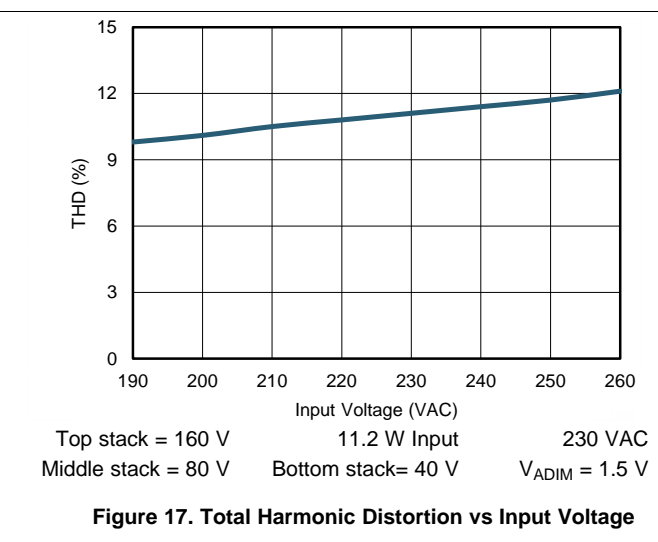
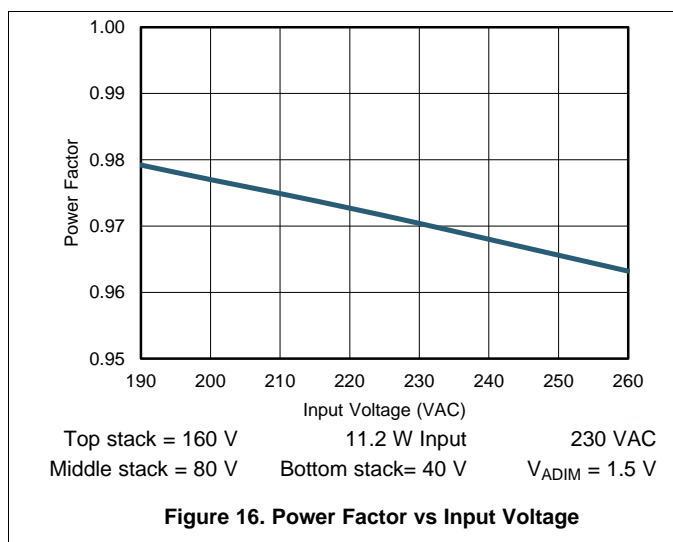
This application requires a 11-W input power, high-efficiency, phase-dimmable LED lamp for use on 230-V systems.

8.2.2.2 Detailed Design Procedure

The TPS92411 components are chosen using the guidelines in the TPS92411 datasheet. Most of the values used for the TPS92410 are recommended values for any 230-V system. The input voltage should be connected directly to rectified AC while the MULT pin is connected to a 4-M Ω , 30.1-k Ω resistor divider between rectified AC and ground. The VREF pin should have a 0.1- μ F capacitor connected to ground to provide decoupling. The VCC pin should be decoupled using a 10- μ F ceramic capacitor to ground and the COMP pin should have a 4.7- μ F ceramic capacitor to ground. Connect a 0.1- μ F ceramic capacitor from the CPS pin to ground. Connect a 1- μ F ceramic capacitor from CDD to ground to enable phase dimmable operation. This results in a 150 ms dimmer detect time constant. The over-voltage protection using the DOV pin can be set using Equation 3. This case includes a MOSFET drain over-voltage level of approximately 51 V. A 4.7- μ F capacitor should be placed in parallel with a 121-k Ω resistor from the DOV pin to ground to set a time constant and for filtering for all applications.

Choose R_{DRAIN} for the appropriate voltage, this case uses a value of 4-M Ω . A 10- Ω resistor in series with a 1- μ F ceramic capacitor from GDL to CS adds stability and helps reduce EMI. A diode should be placed from the center point of these two components to the VCC pin to clamp the voltage on the GDL pin and the CS pin that can become high with some forward phase dimmers. A rating of at least 20 V and 100 mA is recommended with a peak-repetitive current rating of at least 2 A. A 55-k Ω resistor should be connected between the MOSFET source and the CS pin for additional protection. Connect a 30.1-k Ω resistor from the TSNS pin to the VREF pin. The NTC thermistor to ground should be selected so that the desired foldback temperature results in a thermistor value of 30.1 k Ω . R_{CS} is then calculated using Equation 1. R_{CS} = 30.1 Ω is very close and was chosen for this design.

8.2.2.3 Application Curves



9 Power Supply Recommendations

For testing purposes any benchtop adjustable AC power supply with a power rating higher than what is required by the circuit is suitable. An example would be an Hewlett Packard 6811B or equivalent. An isolated supply is recommended for safety purposes.

10 Layout

Proper layout is important in any regulator design. The TPS92410 is a linear regulator which simplifies layout compared to a switching regulator, however some consideration should be taken.

10.1 Layout Guidelines

Components between CPS, CDD, DOV, COMP, VREF, MULT, and VCC to ground (GND) should be placed directly next to the device as shown in [Figure 18](#). The linear MOSFET as well as the GDL and CS traces should be placed as close the TPS92410 as possible as well.

10.2 Layout Example

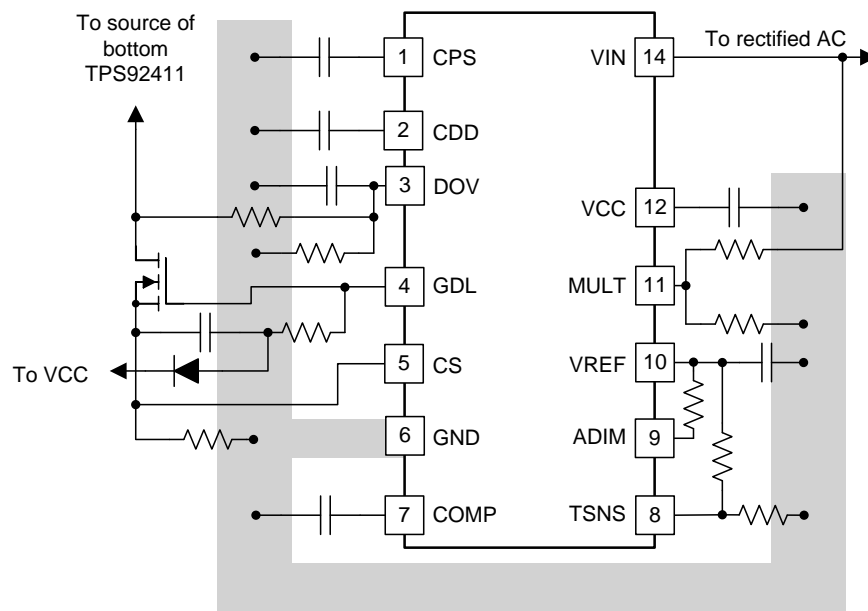


Figure 18. Recommended Component Placement

11 器件和文档支持

11.1 商标

11.2 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.3 术语表

[SLYZ022](#) — *TI* 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

12 机械封装和可订购信息

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| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS92410D | ACTIVE | SOIC | D | 13 | 50 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 150 | TPS92410D | Samples |
| TPS92410DR | ACTIVE | SOIC | D | 13 | 2500 | RoHS & Green | NIPDAU | Level-2-260C-1 YEAR | -40 to 150 | TPS92410D | Samples |

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(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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